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APPLICATION NO.		FII	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
	10/771,566	0	02/03/2004	Nobuaki Teraguchi	245402008300	3733	
	25226	7590	04/27/2005		EXAM	IINER	
	MORRISON 755 PAGE M		RSTER LLP		PAREKH, NITIN		
	PALO ALTO, CA 94304-1018				ART UNIT	PAPER NUMBER	
,					2811		

DATE MAILED: 04/27/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application	1 No.	Applicant(s)	- He							
•	10/771,566		TERAGUCHI, NOBUAK	i .							
Office Action Summary	Examiner		Art Unit								
	Nitin Parek	n	2811								
The MAILING DATE of this commu Period for Reply	nication appears on the	cover sheet with the c	correspondence address								
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).											
Status											
1)⊠ Responsive to communication(s) fi	led on <u>22 February 200</u>	<u>5</u> .									
2a) This action is FINAL.	2b)⊠ This action is no	n-final.									
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.											
Disposition of Claims		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,									
4) ☑ Claim(s) <u>1-5</u> is/are pending in the a 4a) Of the above claim(s) <u>5</u> is/are w 5) ☐ Claim(s) is/are allowed. 6) ☑ Claim(s) <u>1-4</u> is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restr	rithdrawn from consider										
Application Papers											
9)☐ The specification is objected to by t	he Examiner.										
10)⊠ The drawing(s) filed on <u>03 February 2004</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.											
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.											
							Priority under 35 U.S.C. § 119				
							 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). 				
* See the attached detailed Office acti	•	• • •	ed.								
1) Notice of References Cited (PTO-892)		4) Interview Summary	(PTO-413)								
 2) Notice of Draftsperson's Patent Drawing Review (3) Information Disclosure Statement(s) (PTO-1449 of Paper No(s)/Mail Date <u>02-03-04</u>. 	(PTO-948) or PTO/SB/08)	Paper No(s)/Mail D									
J.S. Patent and Trademark Office PTOL-326 (Rev. 1-04)	Office Action Summar	,	Part of Paper No./Mail	Date 4							

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DETAILED ACTION

Election/Restriction

1. Applicant's election without traverse of Group I, claims 1-4 in Paper No. 3 is acknowledged

Claim Rejections - 35 USC § 102

- 2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:
 - (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1, 2 and 4 are rejected under 35 U.S.C. 102(e) as being anticipated by Huang et al. (US Pat. 6693352).

Regarding claims 1, 2 and 4, Huang et al. disclose a contact/electrode structure employing a nitride based semiconductor of III-V group compound (see Fig. 7), the structure comprising:

- a nitride-based semiconductor layer of III-V group compound (35 in Fig. 7; Col. 4, lines 40-47)
- a pad/electrode metal (38A in Fig. 7; Col. 5, lines 45-53), and

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- a metal oxide (see 37A in Fig. 7) such as indium oxide, zinc oxide, etc. being inserted between the nitride-based semiconductor layer of III-V group compound and the pad/electrode metal, the indium oxide including the metal indium and inherently allowing/permitting formation of a nitride semiconductor
(Fig. 7; Col. 10, lines 42-60; Col. 4, line 24- Col. 5, line 60).

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claim 3 is rejected under 35 U.S.C. 103(a) as being unpatentable over Huang et al. (US Pat. 6693352) in view of Steekl et al. (US Pat. Application Pub. 2003/0230970).

Regarding claim 3, Huang et al. teach the entire claimed structure as applied to claim 1 above, except the metal oxide being a semiconductor having a bandgap of less than 3.0 eV.

Steekl et al. teach conventional semiconductor material including zinc oxide having a bandgap of about 2 eV or more to achieve the desired electrical parameters and optical performance (section 0023).

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It would have been obvious to a person of ordinary skill in the art at the time

invention was made to incorporate the metal oxide being a semiconductor having a

bandgap of less than 3.0 eV as taught by Steekl et al. so that the electrical and optical

performance can be improved in Huang et al's electrode.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Nitin Parekh whose telephone number is 571-272-1663.

The examiner can normally be reached on 09:00AM-05:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Eddie Lee can be reached on 571-272-1732. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9318.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is 703-308-

0956.

NP

NITIN PAREKH

04-20-05

PRIMARY EXAMINER

TECHNOLOGY CENTER 2800